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BAT54WT1G
Schottky Barrier Diode

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Extremely Low Forward Voltage − 0.35 V (Typ) @ I_F = 10 mAdc
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant*

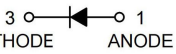
MAXIMUM RATINGS (T_J = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	30	V
Forward Power Dissipation @ T_A = 25°C Derate above 25°C	P_F	 200 1.6	 mW mW/°C
Forward Current (DC)	I_F	200 Max	mA
Non−Repetitive Peak Forward Current, t_p < 10 msec	I_{FSM}	 600	mA
Repetitive Peak Forward Current Pulse Wave = 1 sec, Duty Cycle = 66%	I_{FRM}	300	mA
Junction Temperature	T_J	−55 to 125	°C
Storage Temperature Range	T_{stg}	−55 to +150	°C

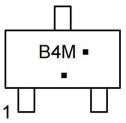
30 VOLT
SCHOTTKY BARRIER
DETECTOR AND SWITCHING
DIODE



SOT−323



MARKING DIAGRAM



B4 = Device Code
M = Date Code*
▪ = Pb−Free Package

(Note: Microdot may be in either location)

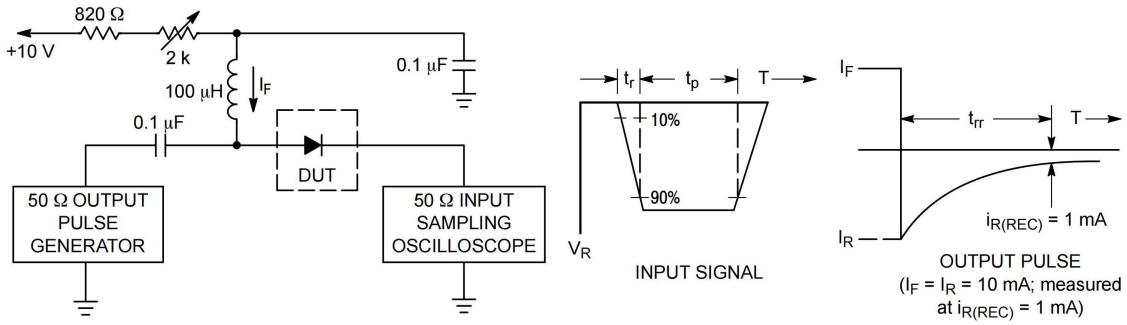
*Date Code orientation may vary depending up-on manufacturing location.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage (I_R = 10 μA)	$V_{(BR)R}$	30	–	–	V
Total Capacitance (V_R = 1.0 V, f = 1.0 MHz)	C_T	–	7.6	10	pF
Reverse Leakage (V_R = 25 V)	I_R	–	0.5	2.0	μAdc
Forward Voltage (I_F = 0.1 mA) (I_F = 1.0 mA) (I_F = 10 mA) (I_F = 30 mA) (I_F = 100 mA)	V_F	 – – – – –	 0.22 0.29 0.35 0.41 0.52	 0.24 0.32 0.40 0.50 0.80	V
Reverse Recovery Time (I_F = I_R = 10 mAdc, $I_{R(REC)}$ = 1.0 mAdc, Figure 1)	t_{rr}	–	–	5.0	ns



Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10 mA.
2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10 mA.
3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

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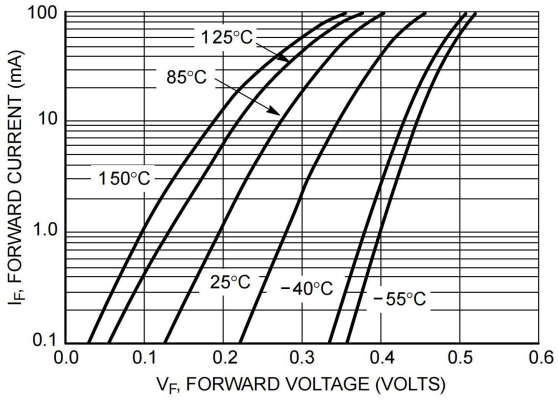


Figure 2. Forward Voltage

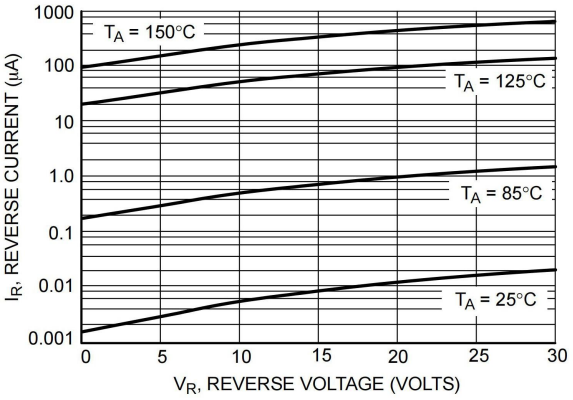


Figure 3. Leakage Current

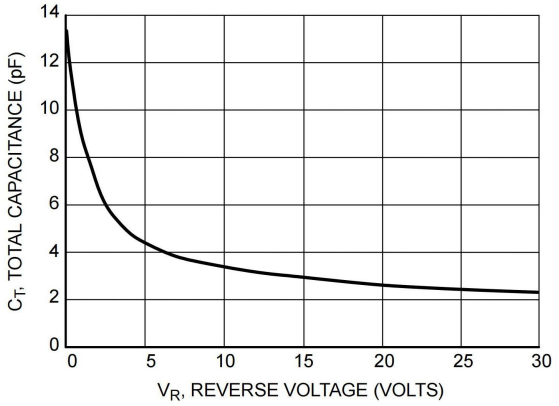


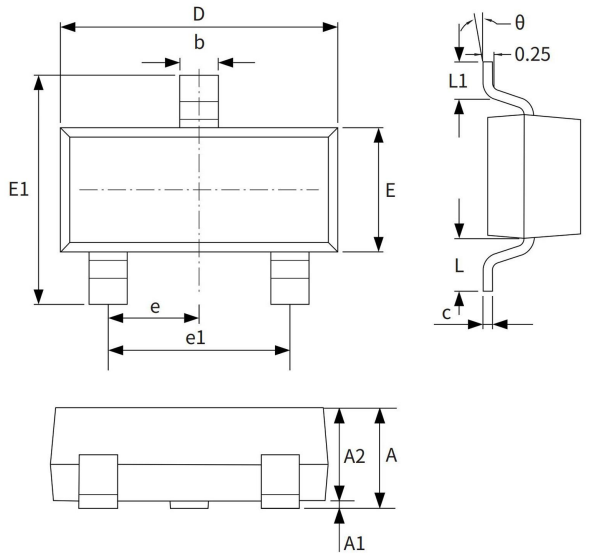
Figure 4. Total Capacitance

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Ordering Information

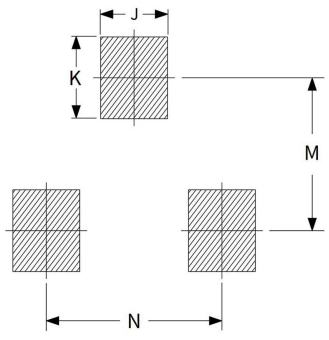
PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOT-323	R1	0.005	3000	30000	240000	7''

Package Outline Dimensions (SOT-323)



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.90	1.10	0.035	0.043
A1	-	0.10	-	0.004
A2	0.90	1.00	0.035	0.039
b	0.15	0.40	0.012	0.020
c	0.10	0.25	0.004	0.010
D	1.80	2.20	0.071	0.087
E	1.15	1.35	0.045	0.053
E1	2.15	2.45	0.085	0.096
e	0.650TYP		0.026TYP	
e1	1.20	1.40	0.047	0.055
L	0.525REF		0.021REF	
L1	0.26	0.46	0.010	0.018
θ	-	8°	-	8°

Suggested Pad Layout



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
J	0.65	0.75	0.026	0.030
K	0.85	0.95	0.033	0.037
M	2.15	2.25	0.073	0.077
N	1.25	1.35	0.049	0.053